

Title (en)  
OPTOELECTRONIC SENSOR

Title (de)  
OPTOELEKTRONISCHER SENSOR MIT EINEM EINEN LICHTEMPFLINDLICHEN BEREICH AUFWEISENDEN HALBLEITERSUBSTRAT

Title (fr)  
CAPTEUR OPTOELECTRONIQUE

Publication  
**EP 1934637 A2 20080625 (DE)**

Application  
**EP 06806040 A 20061004**

Priority  
• EP 2006009609 W 20061004  
• DE 202005015973 U 20051010

Abstract (en)  
[origin: WO2007042191A2] The aim of the invention is to create a novel optoelectronic sensor. To this end, the inventive sensor (30), especially for using in a reflection light scanner, is provided with at least one semiconductor substrate (35) comprising at least one light-sensitive region, at least two collecting regions (50, 60), and an electrically controllable device (40-43, 70-73) for generating at least two differently oriented drift fields. During operation, the drift fields extend at least partially between the collecting regions (50, 60).

IPC 8 full level  
**G01V 8/20** (2006.01)

CPC (source: EP)  
**G01C 3/08** (2013.01); **G01V 8/12** (2013.01); **H01L 27/1443** (2013.01); **H01L 27/1446** (2013.01); **H01L 31/02024** (2013.01); **H01L 31/103** (2013.01); **H01L 31/12** (2013.01)

Citation (search report)  
See references of WO 2007042191A2

Designated contracting state (EPC)  
AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HU IE IS IT LI LT LU LV MC NL PL PT RO SE SI SK TR

DOCDB simple family (publication)  
**DE 202005015973 U1 20070215**; EP 1934637 A2 20080625; WO 2007042191 A2 20070419; WO 2007042191 A3 20071122

DOCDB simple family (application)  
**DE 202005015973 U 20051010**; EP 06806040 A 20061004; EP 2006009609 W 20061004